

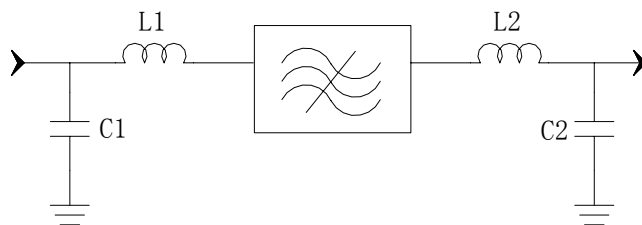
Specifications

Parameter	Unit	Minimum	Typical	Maximum
Center Frequency	MHz	159.92	160	160.08
Insertion Loss	dB	-	23.6	25
3 dB Bandwidth	MHz	2.5	2.56	-
40 dB Bandwidth	MHz	-	3.1	3.2
Absolute Delay	usec	-	4.58	4.6
Passband Variation	dB	-	0.9	1
Group delay Variation ($f_0 \pm 1.15\text{MHz}$)	nsec	-	190	300
Ultimate Rejection	dB	40	45	-
Substrate Material		Quartz		
Ambient Temperature	°C	25		
Package Size		DIP3512 (35.2x12.7x5.2mm ³)		

Notes:

1. All specifications are based on the test circuit shown
2. In production, devices will be tested at room temperature to a guardbanded specification to ensure electrical compliance over temperature
3. Electrical margin has been built into the design to account for the variations due to temperature drift and manufacturing tolerances
4. This is the optimum impedance in order to achieve the performance show

Matching Configuration




L1=38nH L2=33nH

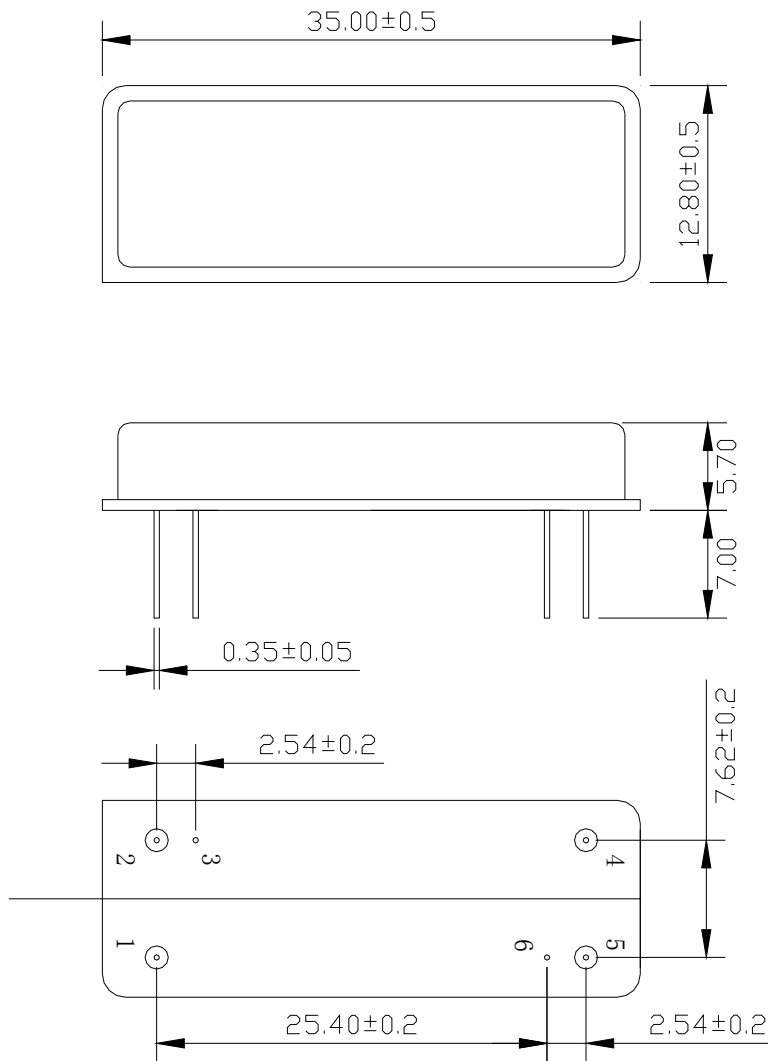
C1=56pF C2=39pF

Source/Load Impedance=50 ohm

Notes - Component values may change depending on board layout.

	SIPAT Co., Ltd. (CETC No. 26 Research Institute) Nanping Huayuan Road No. 14 Chongqing, China, 400060	Part Number	LBS16016	
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Package Dimension

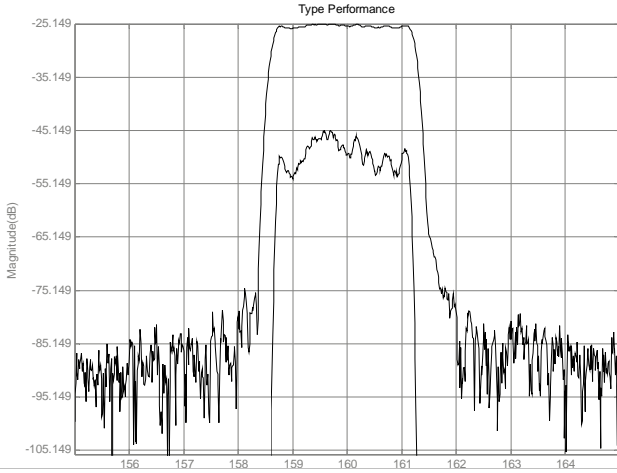


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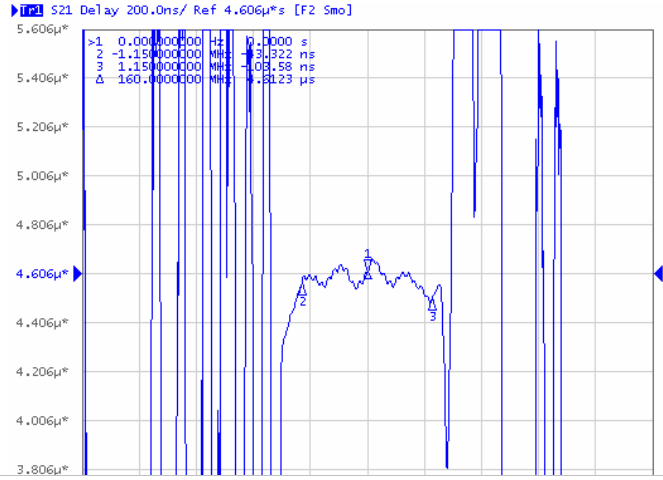
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Typical Performance

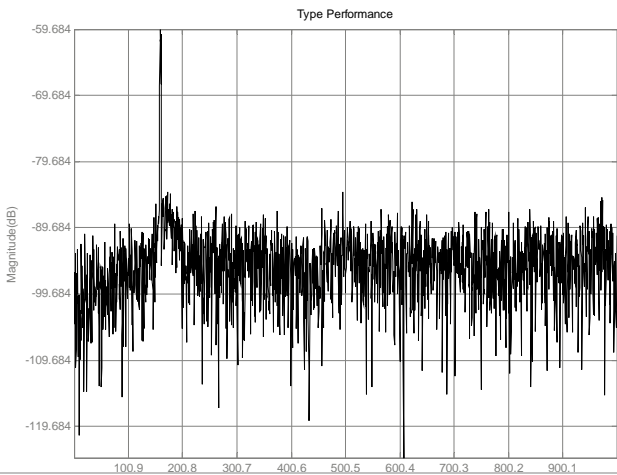
Frequency Respond



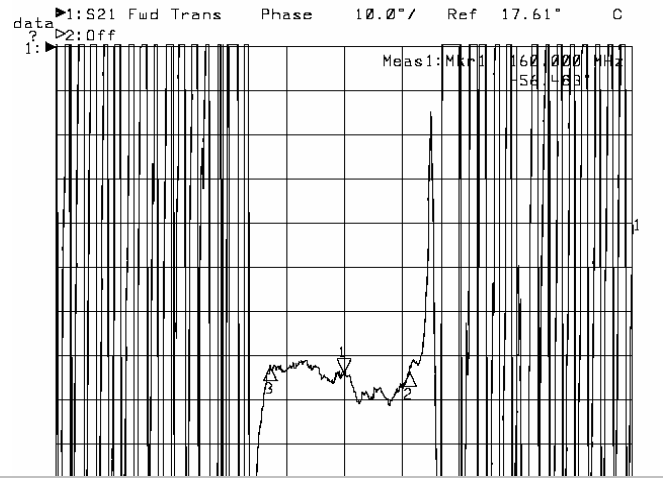
Group delay variation



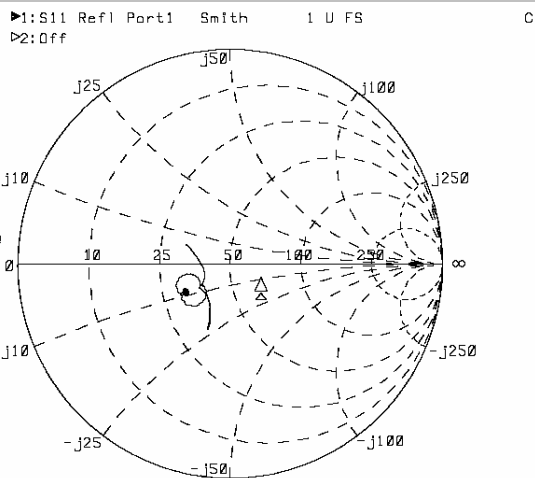
Wideband Respond



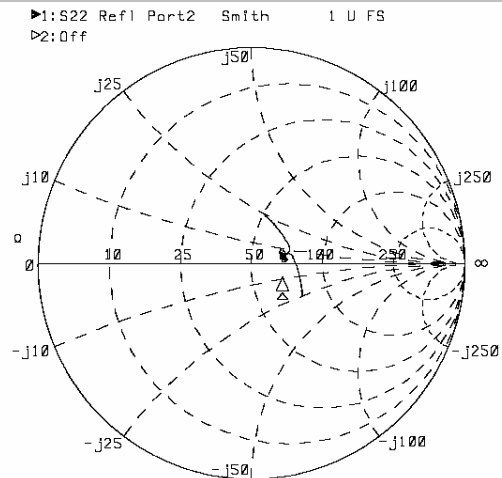
Phase Linearity



Smith Chart S11



Smith Chart S22



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